

### STANDARD RECOVERY DIODES

Stud Version

#### Features

- Wide current range
- High voltage ratings up to 4500V
- High surge current capabilities
- Stud cathode and stud anode version
- Standard JEDEC types
- RoHS Compliant

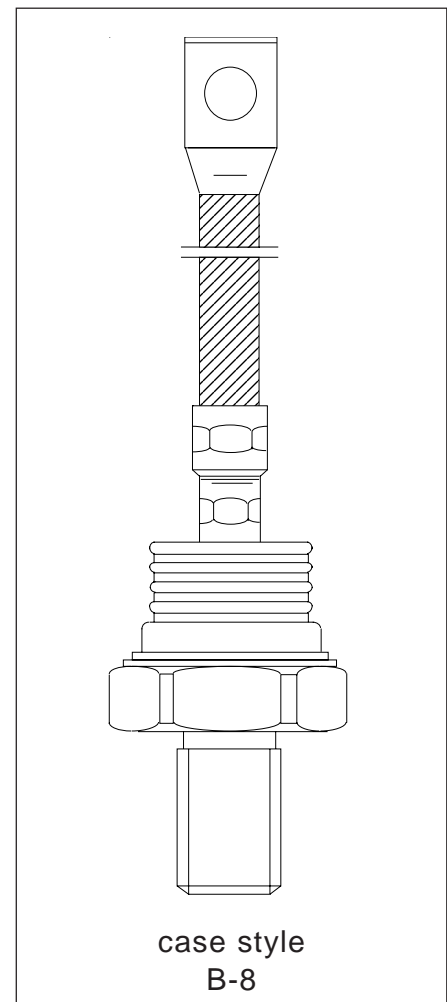
#### Typical Applications

- Converters
- Power supplies
- High power drives
- Auxiliary system supplies for traction applications

#### Major Ratings and Characteristics

Parameters	SD500N/R	Units
$I_{F(AV)}$	475	A
@ $T_C$	55	°C
$I_{F(RMS)}$	745	A
$I_{FSM}$ @ 50Hz	7500	A
@ 60Hz	7850	A
$I^2t$ @ 50Hz	281	KA <sup>2</sup> s
@ 60Hz	257	KA <sup>2</sup> s
$V_{RRM}$ range	3000 to 4500	V
$T_J$	- 40 to 150	°C

475A



**ELECTRICAL SPECIFICATIONS**

Voltage Ratings

Type number	Voltage Code	$V_{RRM}$ , maximum repetitive peak reverse voltage V	$V_{RSM}$ , maximum non-repetitive peak rev. voltage V	$I_{RRM}$ max. @ $T_J = T_J$ max. mA
SD500N/R	30	3000	3100	50
	36	3600	3700	
	40	4000	4100	
	45	4500	4600	

Forward Conduction

Parameter	SD500N/R	Units	Conditions
$I_{F(AV)}$ Max. average forward current @ Case temperature	475	A	180° conduction, half sine wave
	55	°C	
$I_{F(AV)}$ Max. average forward current @ Case temperature	300	A	180° conduction, half sine wave
	100	°C	
$I_{F(RMS)}$ Max. RMS forward current	745	A	DC @ 40°C case temperature
$I_{FSM}$ Max. peak, one-cycle forward, non-repetitive surge current	7500	A	t = 10ms No voltage
	7850		t = 8.3ms reapplied
	6310		t = 10ms 50% $V_{RRM}$
	6600		t = 8.3ms reapplied
$I^2t$ Maximum $I^2t$ for fusing	281	KA <sup>2</sup> s	t = 10ms No voltage
	257		t = 8.3ms reapplied
	199		t = 10ms 50% $V_{RRM}$
	182		t = 8.3ms reapplied
$I^2\sqrt{t}$ Maximum $I^2\sqrt{t}$ for fusing	2810	KA <sup>2</sup> √s	t = 0.1 to 10ms, no voltage reapplied
$V_{F(TO)1}$ Low level value of threshold voltage	0.88	V	(16.7% x $\pi$ x $I_{F(AV)} < I < \pi$ x $I_{F(AV)}$ ), $T_J = T_J$ max.
$V_{F(TO)2}$ High level value of threshold voltage	0.97		( $I > \pi$ x $I_{F(AV)}$ ), $T_J = T_J$ max.
$r_{f1}$ Low level value of forward slope resistance	0.78	mΩ	(16.7% x $\pi$ x $I_{F(AV)} < I < \pi$ x $I_{F(AV)}$ ), $T_J = T_J$ max.
$r_{f2}$ High level value of forward slope resistance	0.72		( $I > \pi$ x $I_{F(AV)}$ ), $T_J = T_J$ max.
$V_{FM}$ Max. forward voltage drop	1.66	V	$I_{pk} = 1000A$ , $T_J = T_J$ max, $t_p = 10ms$ sinusoidal wave

Thermal and Mechanical Specifications

Parameter	SD500N/R	Units	Conditions
T <sub>J</sub> Max. junction operating temperature range	-40 to 150	°C	
T <sub>stg</sub> Max. storage temperature range	-55 to 200		
R <sub>thJC</sub> Max. thermal resistance, junction to case	0.1	K/W	DC operation
R <sub>thCS</sub> Max. thermal resistance, case to heatsink	0.04		Mounting surface, smooth, flat and greased
T Max. allowed mounting torque ±10%	50	Nm	Not lubricated threads
wt Approximate weight	454	g	
Case style	B - 8		See Outline Table

$\Delta R_{thJC}$  Conduction

(The following table shows the increment of thermal resistance R<sub>thJC</sub> when devices operate at different conduction angles than DC)

Conduction angle	Sinusoidal conduction	Rectangular conduction	Units	Conditions
180°	0.012	0.008	K/W	T <sub>J</sub> = T <sub>J</sub> max.
120°	0.014	0.014		
90°	0.017	0.019		
60°	0.025	0.026		
30°	0.042	0.042		

Ordering Information Table

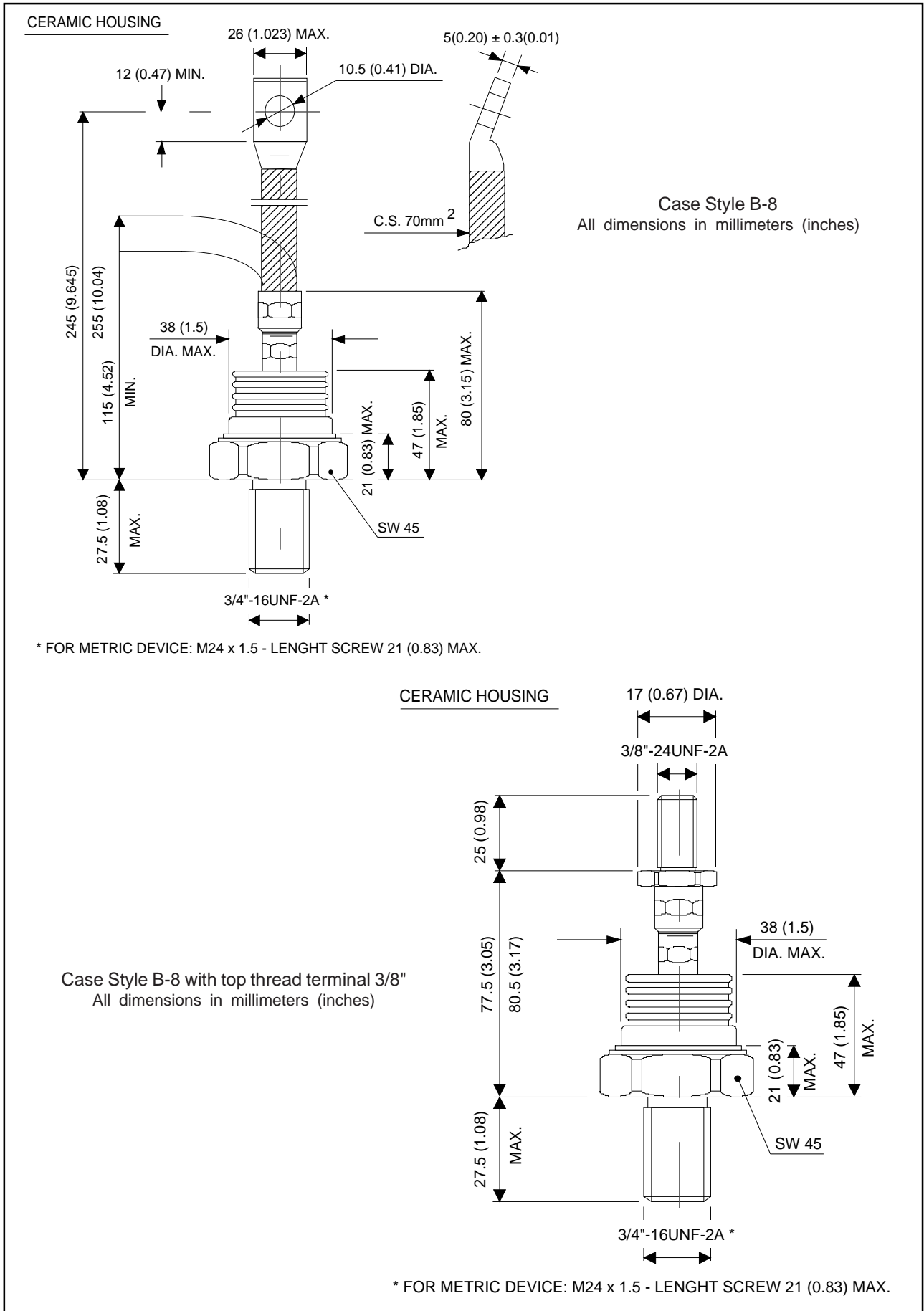
**Device Code**

<b>SD</b>	<b>50</b>	<b>0</b>	<b>N</b>	<b>45</b>	<b>P</b>	<b>S</b>	<b>C</b>
①	②	③	④	⑤	⑥	⑦	⑧

- 1** - Diode
- 2** - Essential part number
- 3** - 0 = Standard recovery
- 4** - N = Stud Normal Polarity (Cathode to Stud)  
R = Stud Reverse Polarity (Anode to Stud)
- 5** - Voltage code: Code x 100 = V<sub>RRM</sub> (See Voltage Ratings table)
- 6** - P = Stud base B-8 3/4" 16UNF-2A  
M = Stud base B-8 M24 X 1.5
- 7** - S = Isolated lead with silicone sleeve  
(Red = Reverse Polarity; Blue = Normal Polarity)  
T = Threaded Top Terminal 3/8" 24UNF-2A  
None = Non isolated lead
- 8** - C = Ceramic Housing

NOTE: Available for rotating applications (Contact factory)

**Outlines Table**



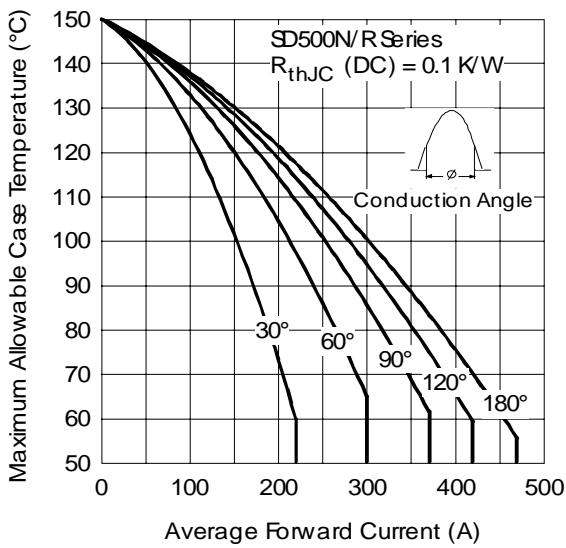


Fig. 1 - Current Ratings Characteristics

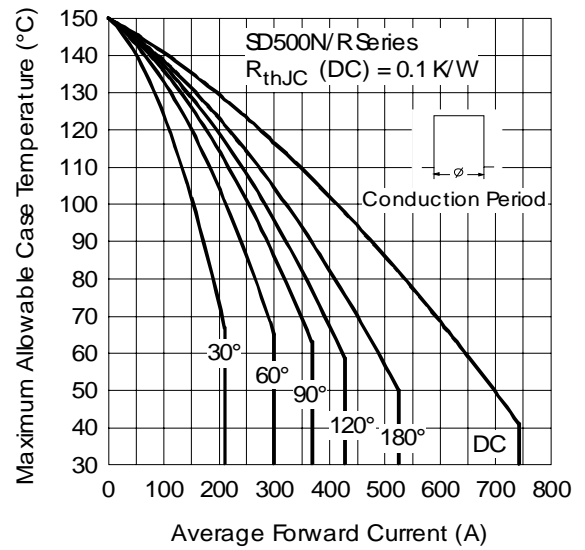


Fig. 2 - Current Ratings Characteristics

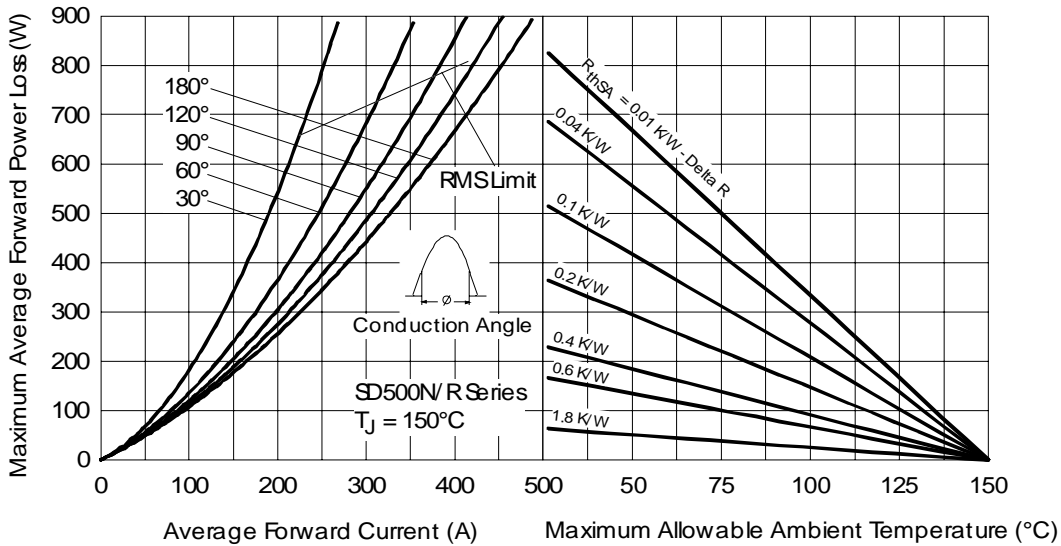


Fig. 3 - Forward Power Loss Characteristics

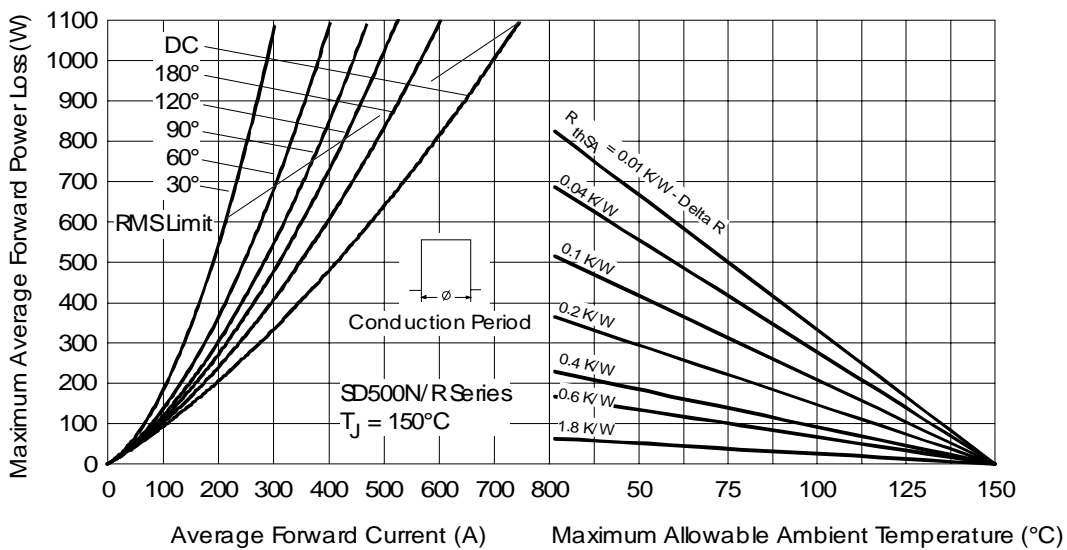


Fig. 4 - Forward Power Loss Characteristics

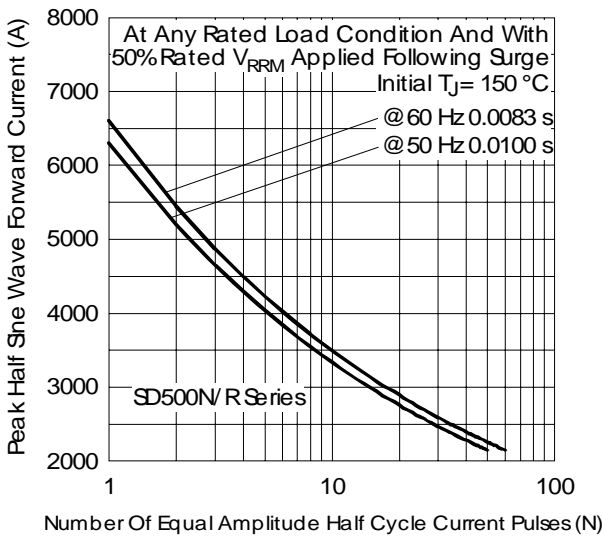


Fig. 5 - Maximum Non-Repetitive Surge Current

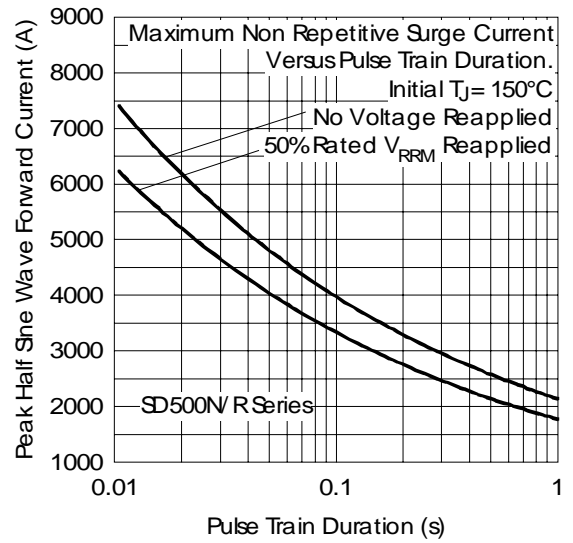


Fig. 6 - Maximum Non-Repetitive Surge Current

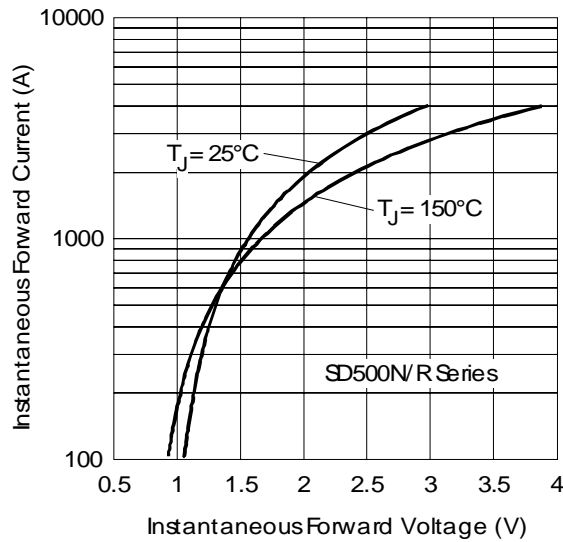


Fig. 7 - Forward Voltage Drop Characteristics

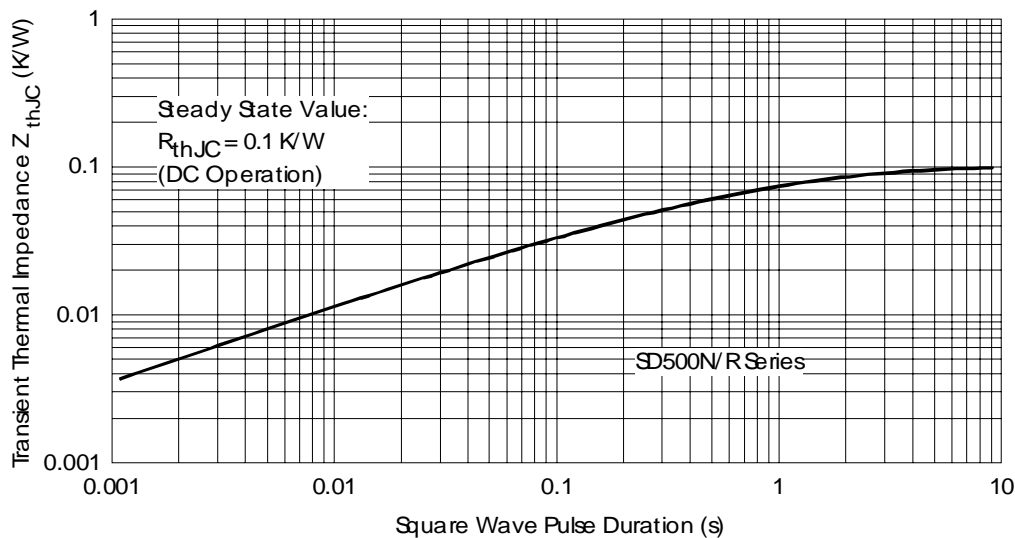


Fig. 8 - Thermal Impedance  $Z_{thJC}$  Characteristics

Data and specifications subject to change without notice.  
This product has been designed and qualified for Industrial Level.  
Qualification Standards can be found on IR's Web site.

International  
**IOR** Rectifier

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[>>Vishay\(威世\)](#)